

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,864,139 B2
DATED : March 8, 2005
INVENTOR(S) : Forbes

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page,

Item [56], **References Cited**, OTHER PUBLICATIONS,

"Shi, Ying," reference, delete "Dialectrics" and insert -- Dielectrics --, therefor.

"Chau," reference, after "CMOS" delete "Tansistors" and insert -- Transistors --, therefor; and after "Electron" delete "." and insert -- , --, therefor.

"Tiwari," reference, delete "Solicon" and insert -- Silicon --, therefor.

Column 7,

Line 63, delete "10⁻¹⁷" and insert -- 10⁻¹⁰ --, therefor.

Column 11,

Line 20, delete " $|IDS| = (\epsilon C_o)(W/L) \frac{(VGS - VT)^2}{2}$ " and insert

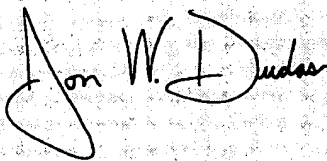
-- " $|IDS| = (\epsilon C_o)(W/L) \frac{(VGS - VT)^2}{2}$ " --, therefor.

Column 16,

Line 59, delete "10⁻¹⁵" and insert -- 10¹⁵ --, therefor.

Signed and Sealed this

Thirty-first Day of May, 2005



JON W. DUDAS

Director of the United States Patent and Trademark Office